

AT45DB641E-MHN2B-T

Data Sheet

NOR Flash Serial-SPI 1.8V/2.5V/3.3V 64M-bit 8M x 8 7ns 8-Pin UDFN EP T/R

Manufacturers	Renesas Technology Corp	
Package/Case	8-UDFN Exposed P	1 the
Product Type	Memory	C.C.
RoHS		
Lifecycle		Images are for reference only

Please submit RFQ for AT45DB641E-MHN2B-T or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

Features

Includes controllable Dual R/W SRAM buffers for maximum flexibility

Standard block architecture with added 256-byte page erase for energy efficient Data Logging

Byte-write provides Serial EEPROM functionality in a Serial NOR Flash device

Extended Vcc operation allows the system memory to operate over the entire voltage range

Ultra-deep power down

Comprehensive security and unique ID features protect the device from outside tampering

Related Products



AT45DB641E-SHN2B-T Renesas Technology Corp SOIC-8



AT45DB021E-SHN-B

Renesas Technology Corp SOIC-8



AT25DF321A-MH-T

Renesas Technology Corp UDFN-8



AT45DB161E-SHD-B

Renesas Technology Corp SOIC-8



AT45DB081E-SSHN-B Renesas Technology Corp SOIC-8



AT45DB081E-SHN-T Renesas Technology Corp SOIC-8



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